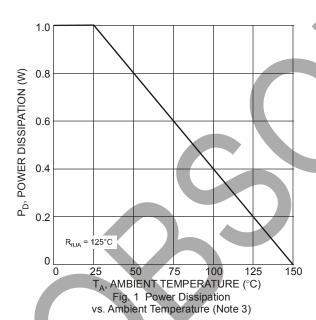
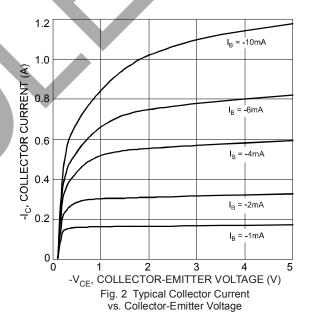


Electrical Characteristics @TA = 25°C unless otherwise specified

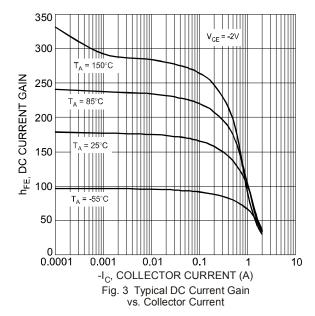
Characteristic	Symbol	Min	Тур	Max	Unit	Conditions
OFF CHARACTERISTICS (Note 4)						
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-25	_	_	V	$I_C = -10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-25	_	_	٧	$I_C = -1 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5	_	_	V	$I_E = -10\mu A, I_C = 0$
Collector Cut-Off Current	I _{CBO}	_	_	-0.1	μΑ	$V_{CB} = -20V, I_{E} = 0$
Emitter Cut-Off Current	I _{EBO}	_	_	-0.1	μΑ	$V_{EB} = -4V, I_{C} = 0$
ON CHARACTERISTICS (Note 4)						
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	-0.15	-0.7	>	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	-0.85	-1.2	V	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
DC Current Gain	h _{FE}	140	_	280		$V_{CE} = -2V, I_{C} = -50mA$
DC Current Gain		40	_	_	ĺ	$V_{CE} = -2V, I_{C} = -1A$
SMALL SIGNAL CHARACTERISTICS						
Transition Frequency	f⊤	_	200		MHz	$V_{CE} = -10V, I_{C} = -50mA$ f = 100MHz
Output Capacitance	C _{ob}	_	12		pF	$V_{CB} = -10V, I_{E} = 0,$ f = 1MHz

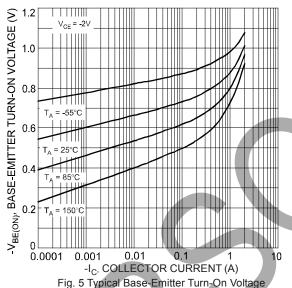
Notes: 4. Measured under pulsed conditions. Pulse width = $300\mu s$. Duty cycle $\leq 2\%$.

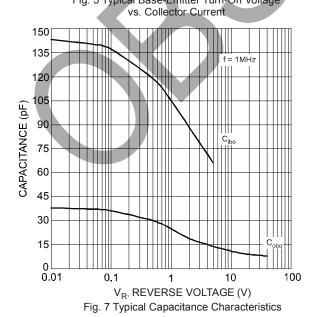












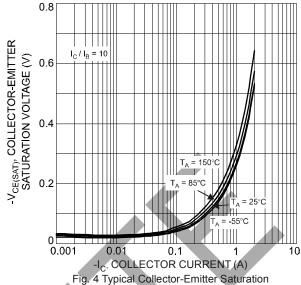


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

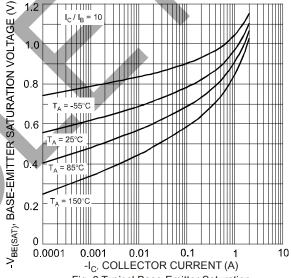


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

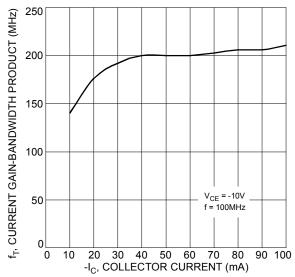


Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current

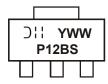


Ordering Information (Note 5)

Part Number	Case	Packaging
2DB1119S-13	SOT89-3L	2500/Tape & Reel

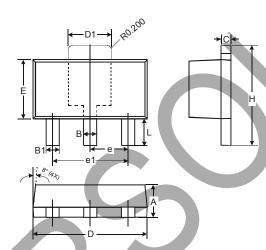
Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



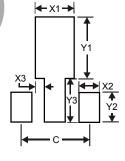
P12BS = Product Type Marking Code YWW = Date Code Marking Y = Last digit of year (ex: 7 = 2007) WW = Week code (01 – 53)

Package Outline Dimensions



SO189-3L				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
C	0.35	0.43		
D	4.40	4.60		
D1	1.52	1.83		
Е	2.29	2.60		
е	1.50 Typ			
e1	3.00 Typ			
Η	3.94	4.25		
L	0.89	1.20		
All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)
X1	1.7
X2	0.9
Х3	0.4
Y1	2.7
Y2	1.3
Y3	1.9
С	3.0



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